

Diode Application

Dr Mohammad Abdur Rashid



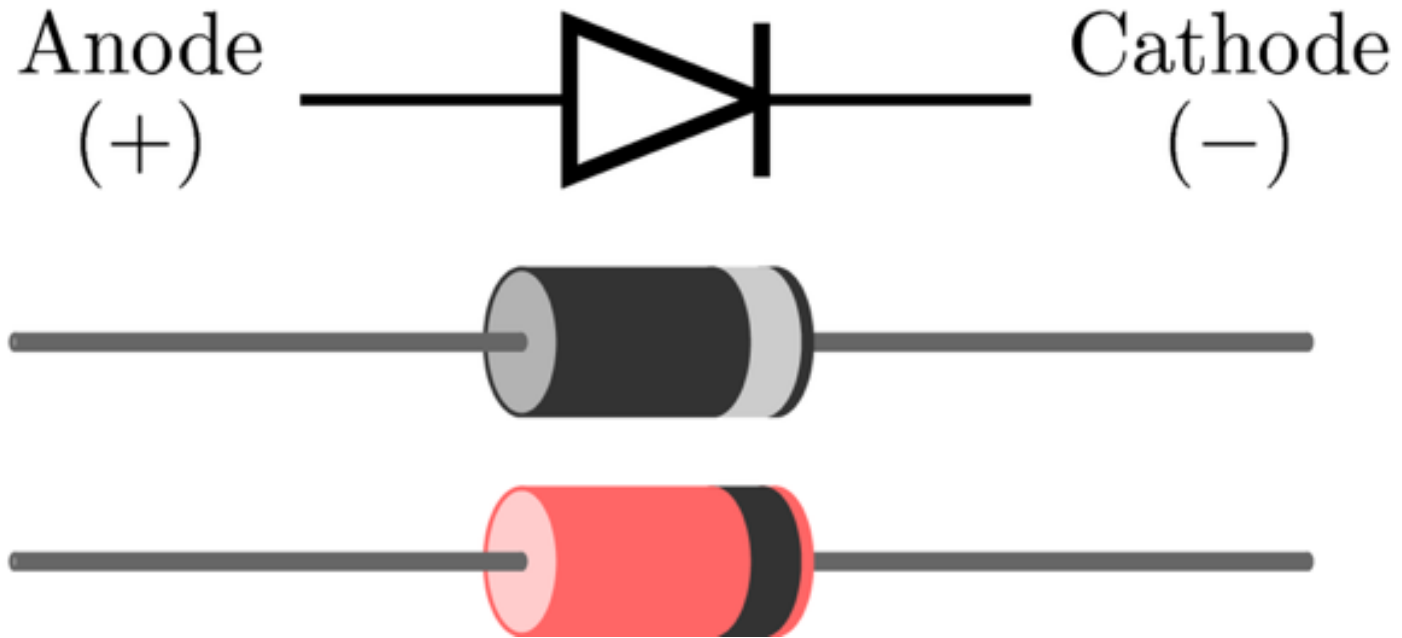
Readings

Electronic Devices and Circuit Theory – Boylestad, Nashelsky

Chapter 2: Diode Applications

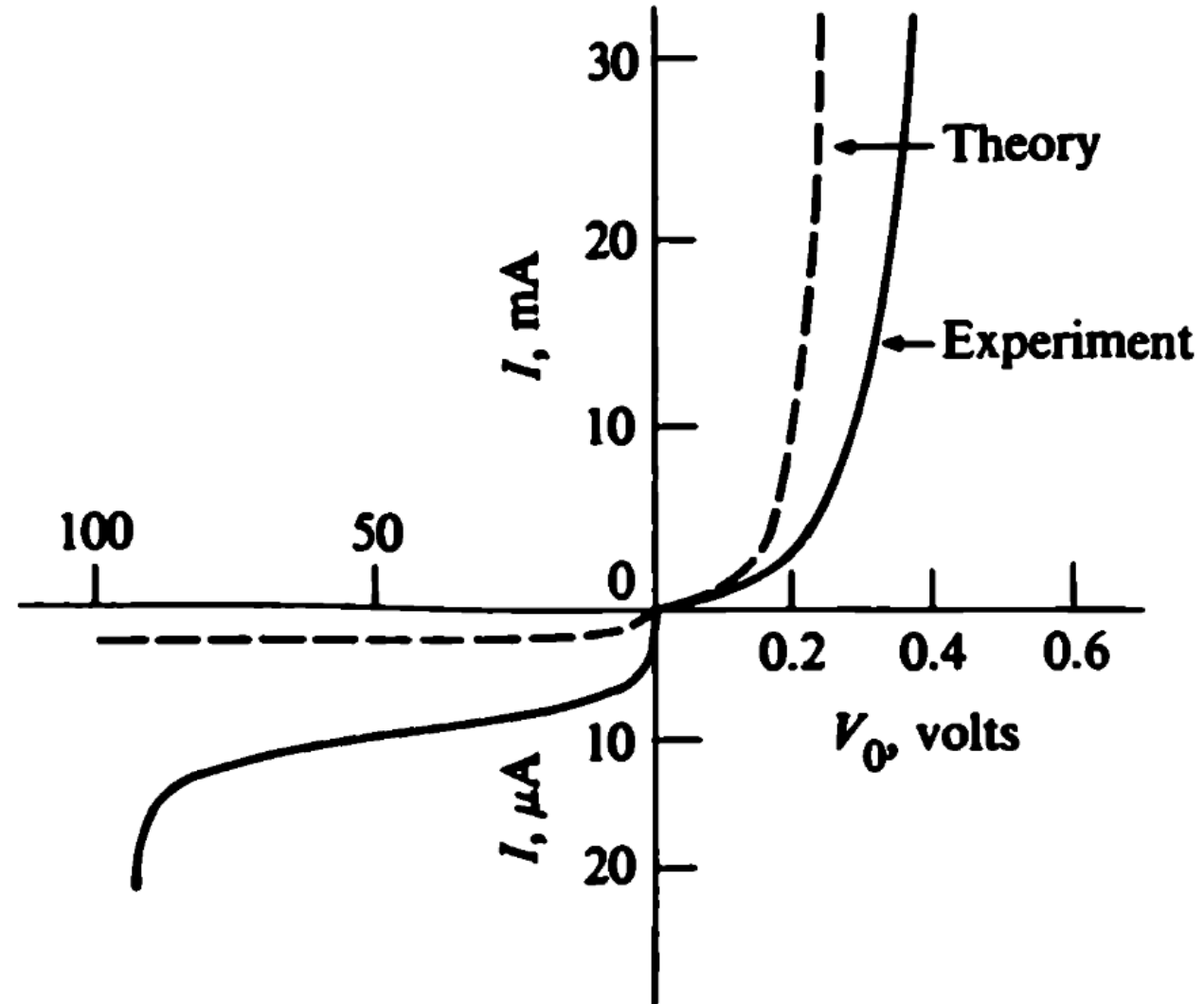


Diode



Current versus voltage characteristics

Elementary Solid State
Physics – Ali Omar

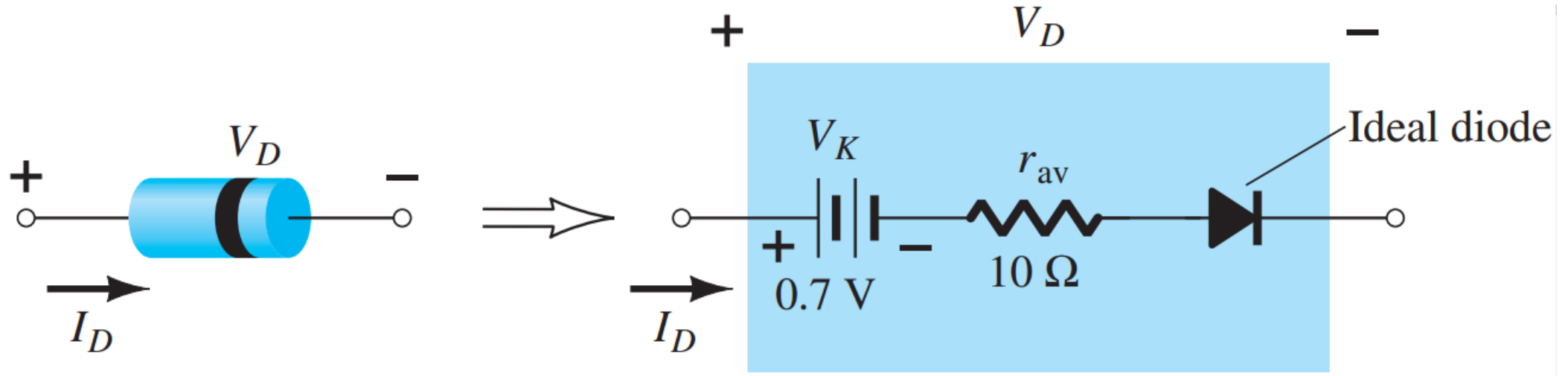


LED residential and commercial lighting



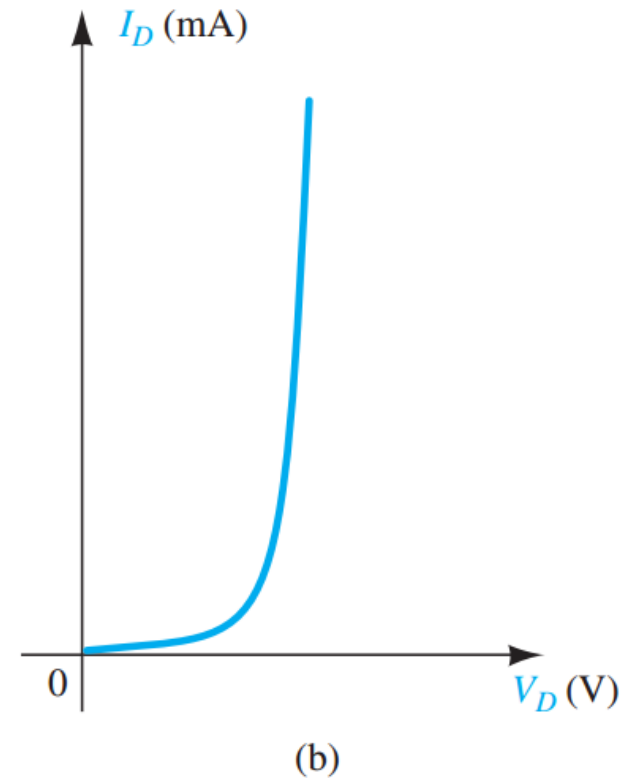
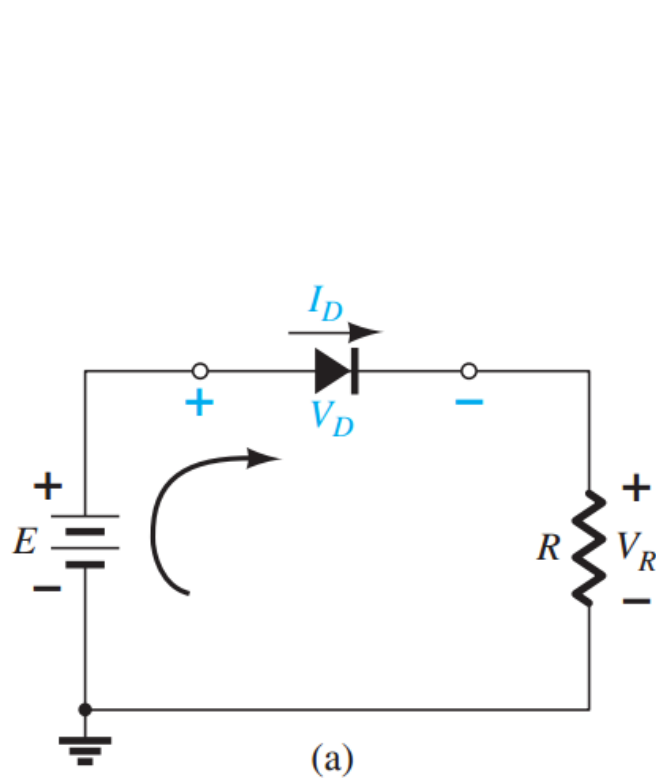
Electronic Devices and Circuit Theory – Boylestad, Nashelsky

Diode symbol



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Load-line analysis



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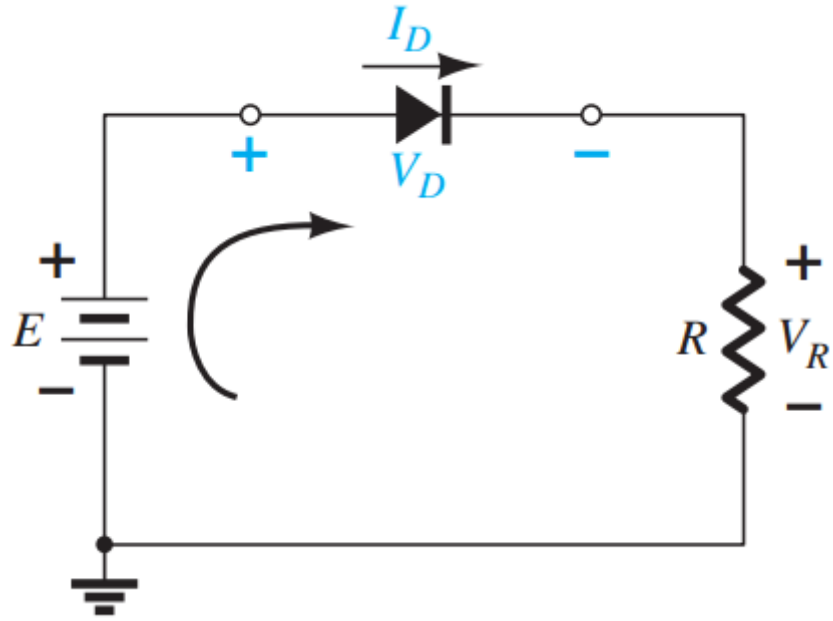
Series diode configuration: (a) circuit; (b) characteristics.

Note

In general, a diode is in the “on” state if the current established by the applied sources is such that its direction matches that of the arrow in the diode symbol, and $V_D \geq 0.7 \text{ V}$ for silicon, $V_D \geq 0.3 \text{ V}$ for germanium, and $V_D \geq 1.2 \text{ V}$ for gallium arsenide.



Applying Kirchhoff's voltage law

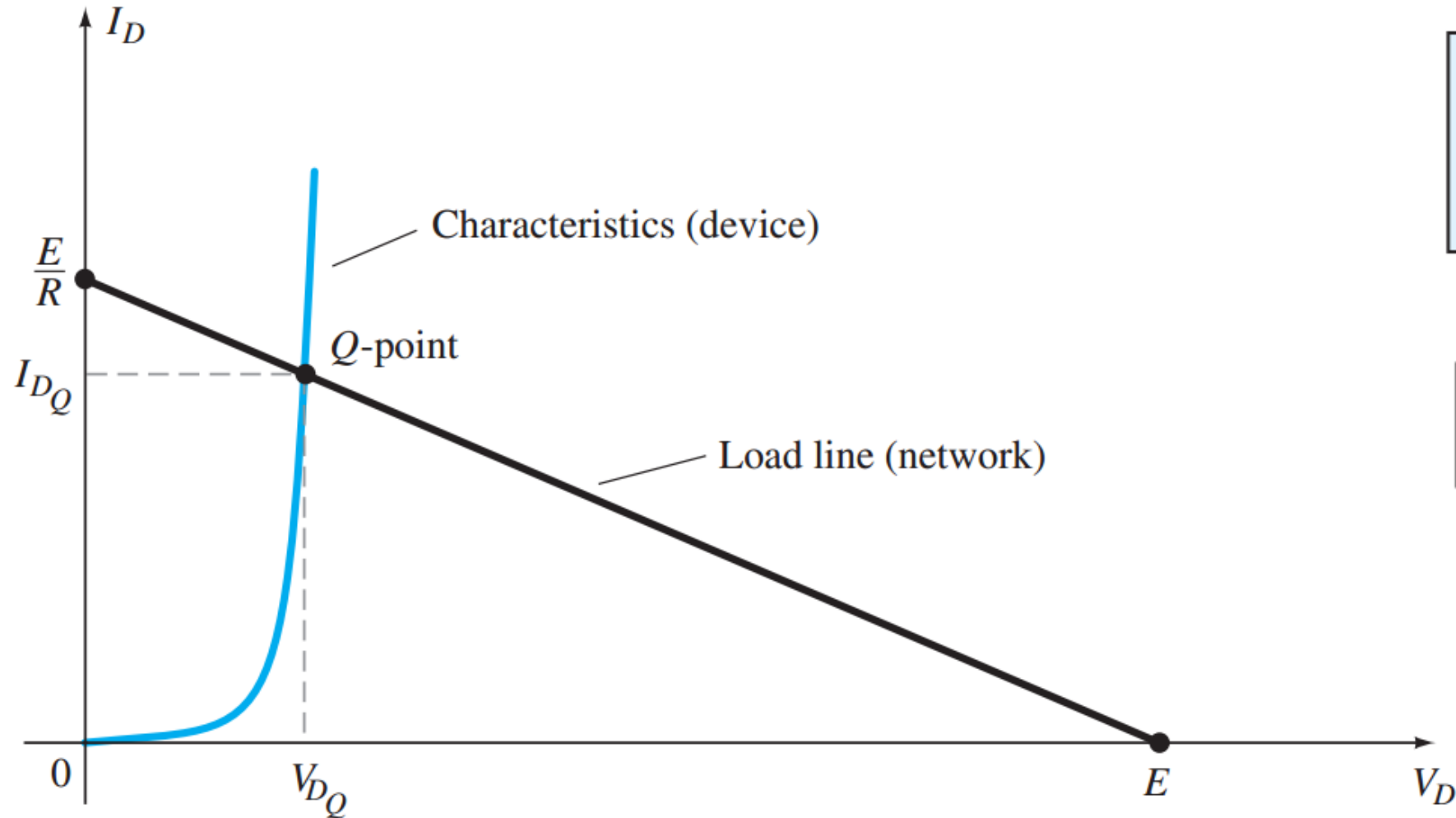


$$E = V_D + I_D R$$

$$I_D = \frac{E}{R} \Big|_{V_D=0 \text{ V}}$$

$$V_D = E \Big|_{I_D=0 \text{ A}}$$

Load line and point of operation

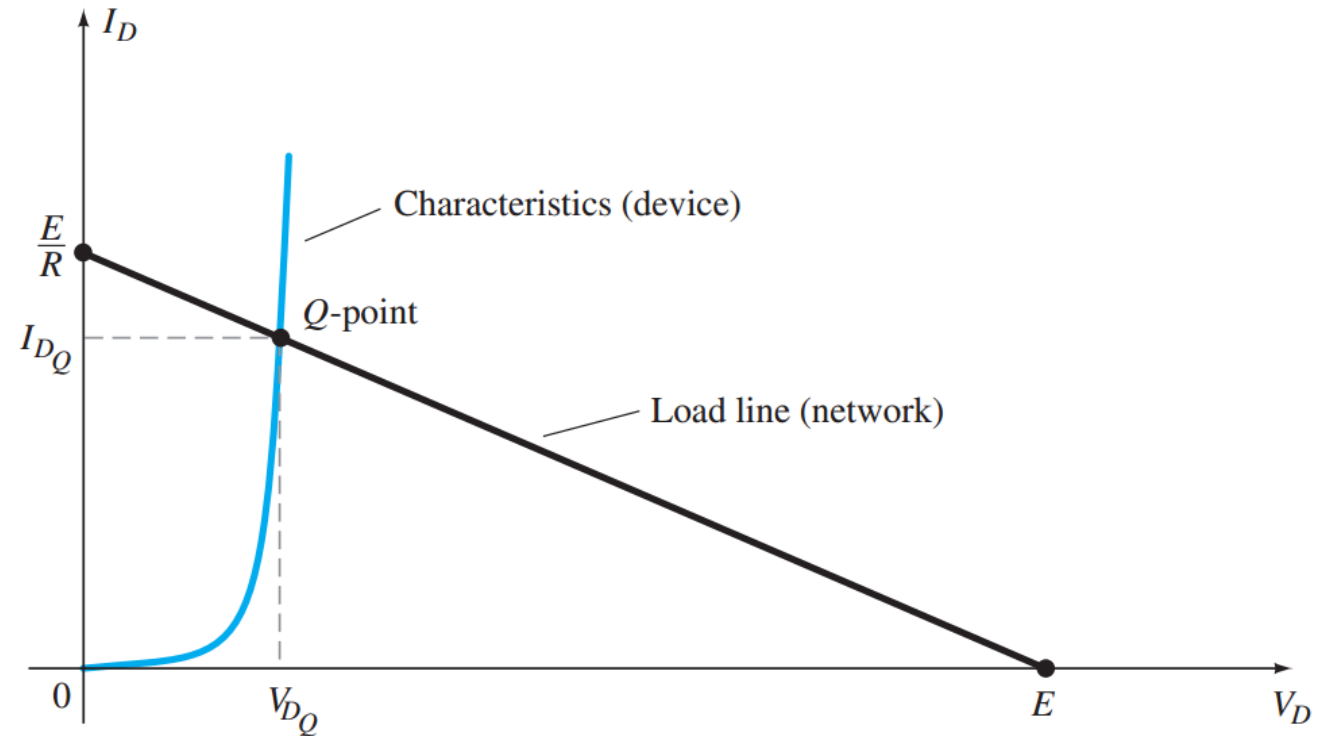


$$I_D = \frac{E}{R} \Big|_{V_D=0 \text{ V}}$$

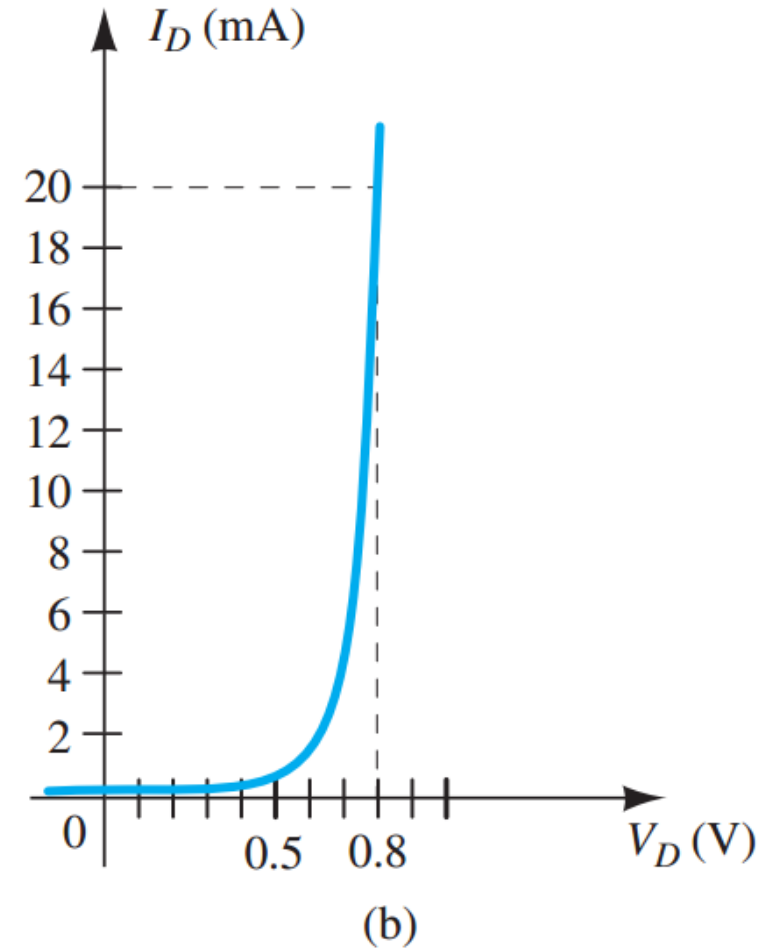
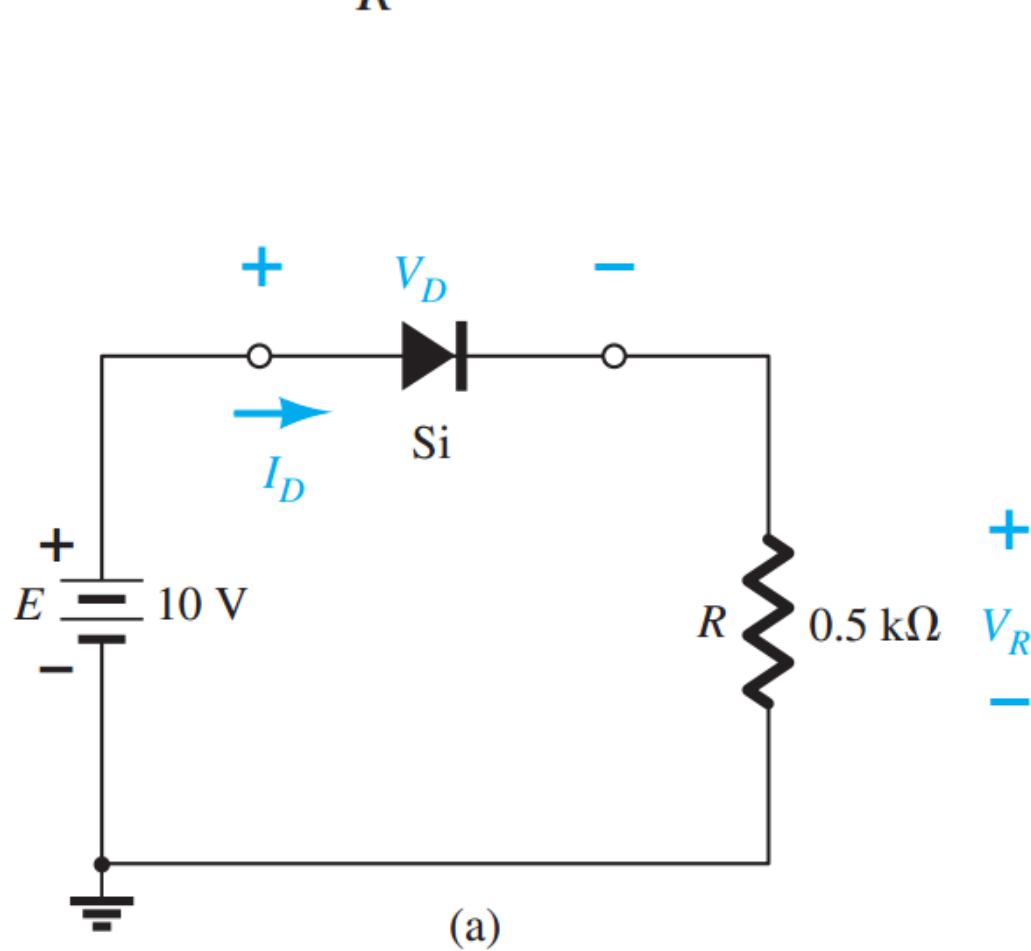
$$V_D = E \Big|_{I_D=0 \text{ A}}$$

Q-point

The point of operation is usually called the quiescent point (abbreviated “Q-point”) to reflect its “still, unmoving” qualities as defined by a dc network.

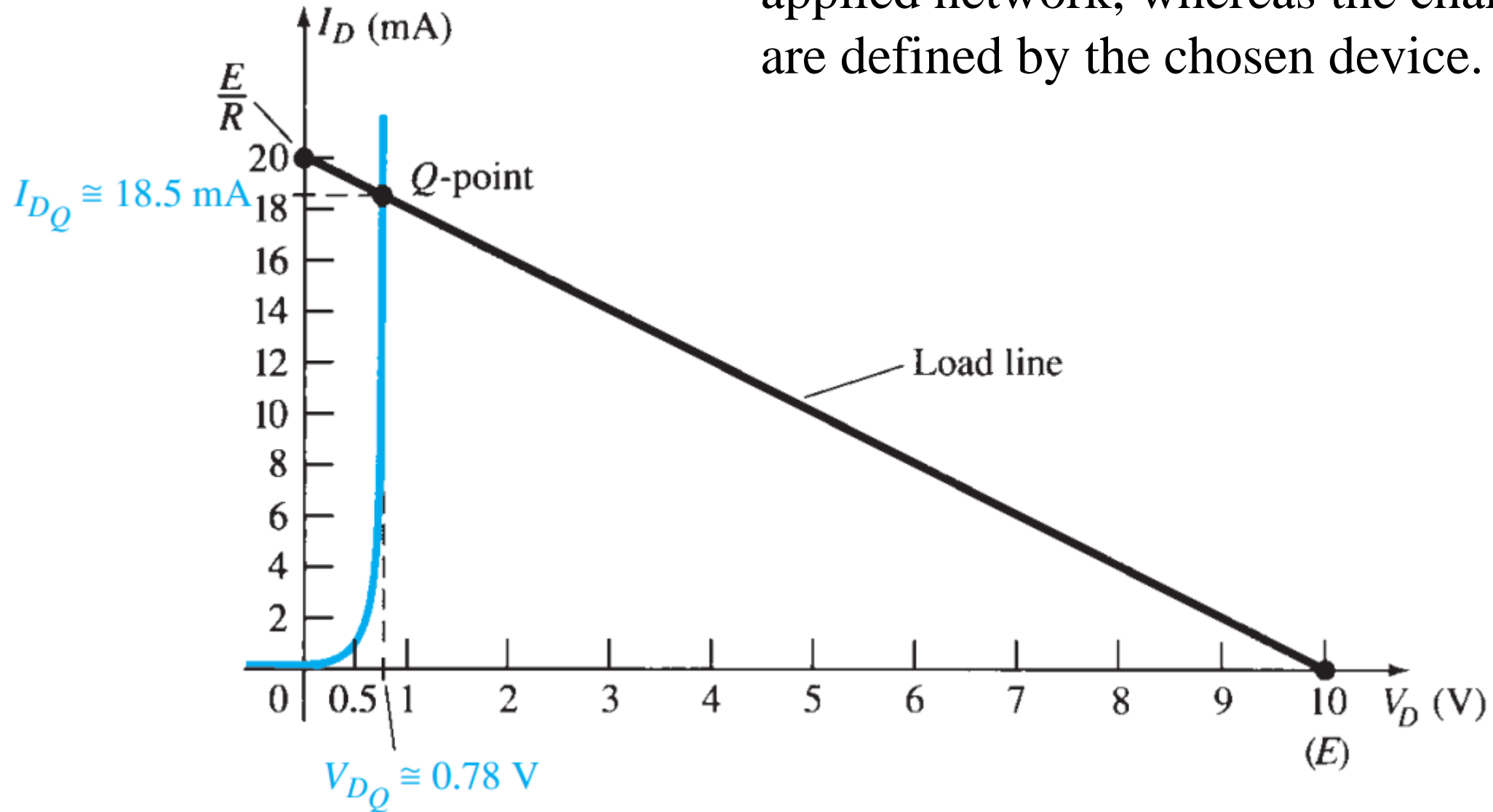


Determine: a. V_{D_Q} and I_{D_Q} .
b. V_R .



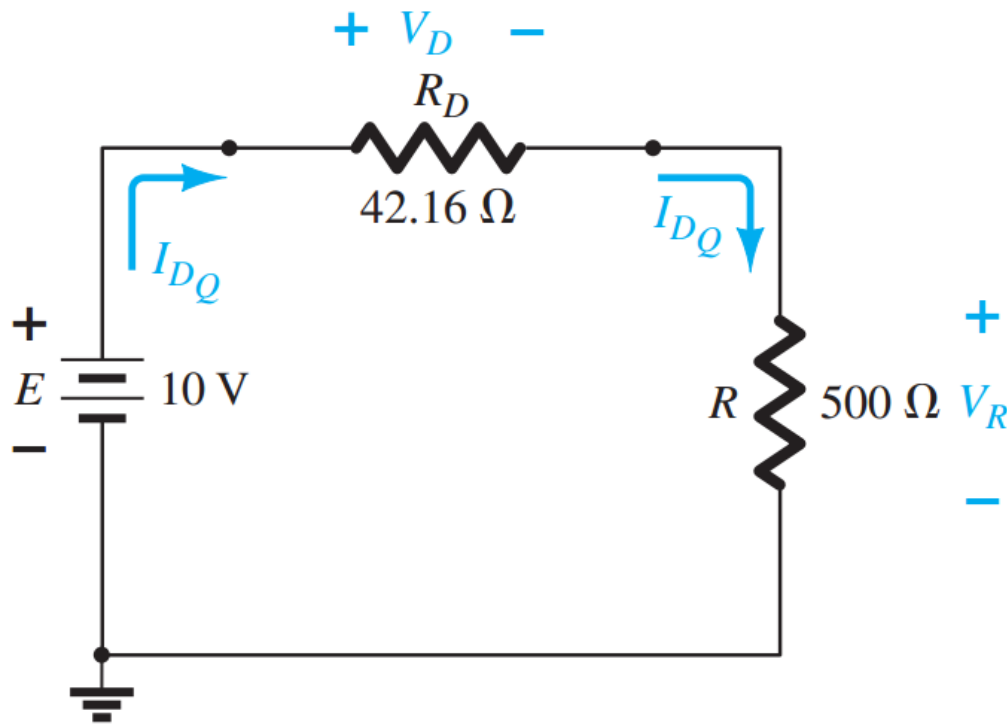
(a) Circuit; (b) characteristics.

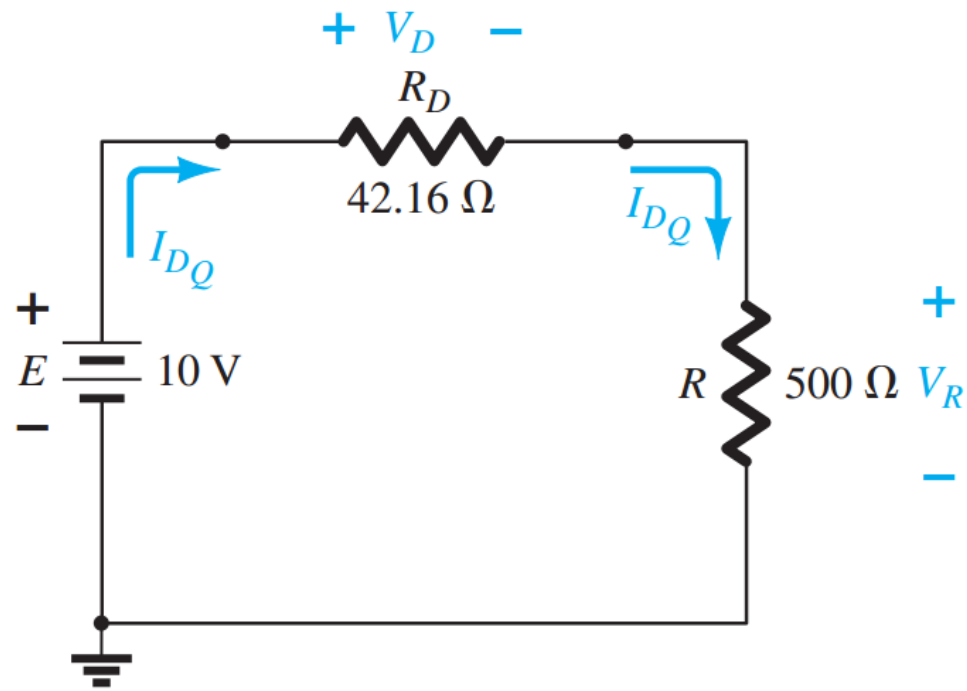
The load line is determined solely by the applied network, whereas the characteristics are defined by the chosen device.



Using the Q -point values, the dc resistance

$$R_D = \frac{V_{DQ}}{I_{DQ}} = \frac{0.78 \text{ V}}{18.5 \text{ mA}} = 42.16 \Omega$$

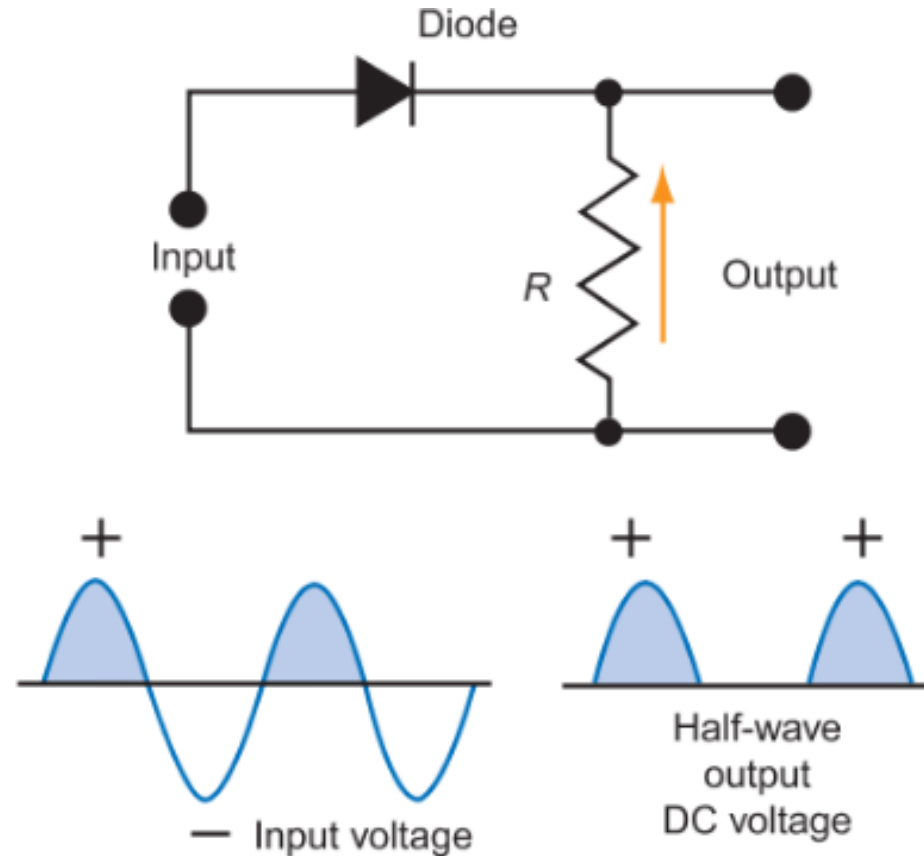




$$I_D = \frac{E}{R_D + R} = \frac{10\text{ V}}{42.16\ \Omega + 500\ \Omega} = \frac{10\text{ V}}{542.16\ \Omega} \cong \mathbf{18.5\text{ mA}}$$

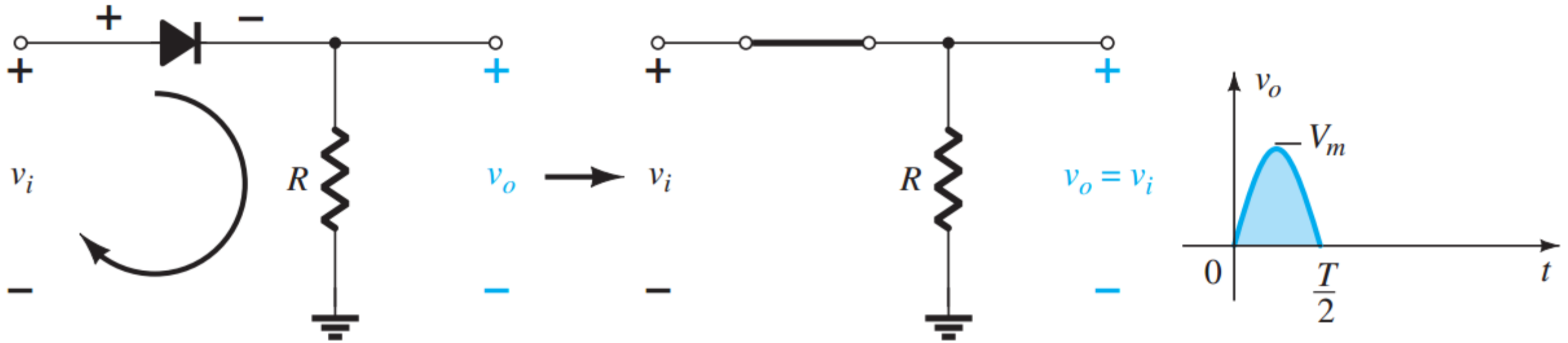
$$V_R = \frac{RE}{R_D + R} = \frac{(500\ \Omega)(10\text{ V})}{42.16\ \Omega + 500\ \Omega} = \mathbf{9.22\text{ V}}$$

Half-wave rectifier



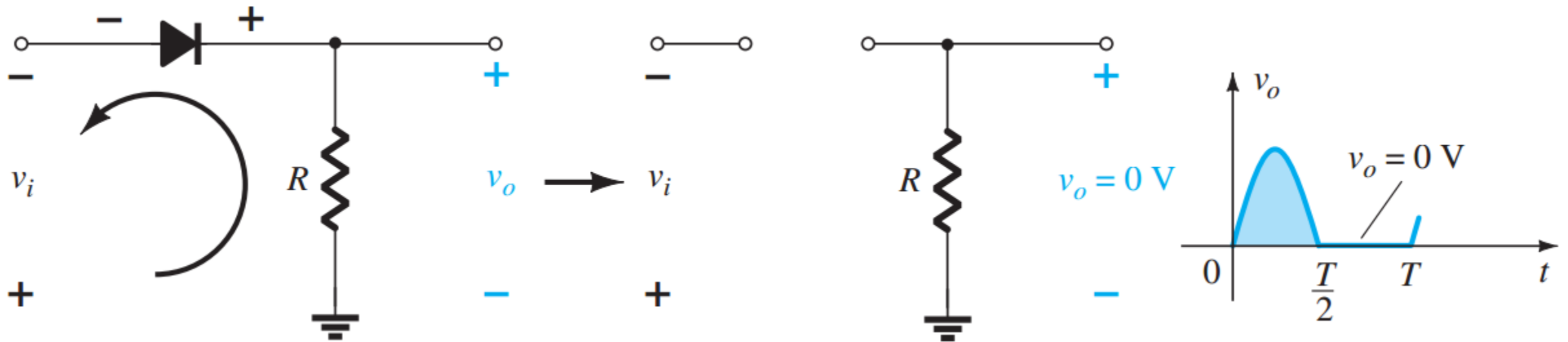
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Half-wave rectifier



Electronic Devices and Circuit Theory – Boylestad, Nashelsky

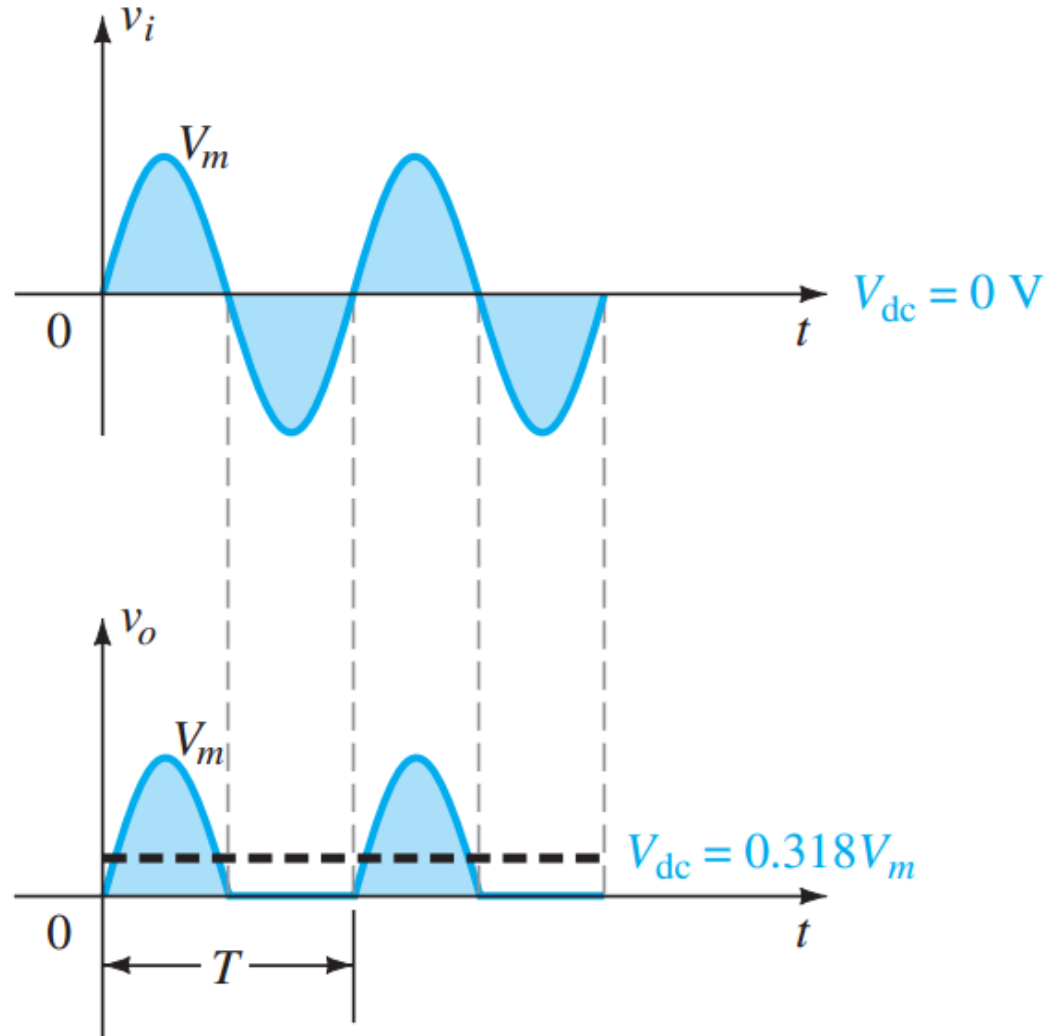
Half-wave rectifier



Electronic Devices and Circuit Theory – Boylestad, Nashelsky



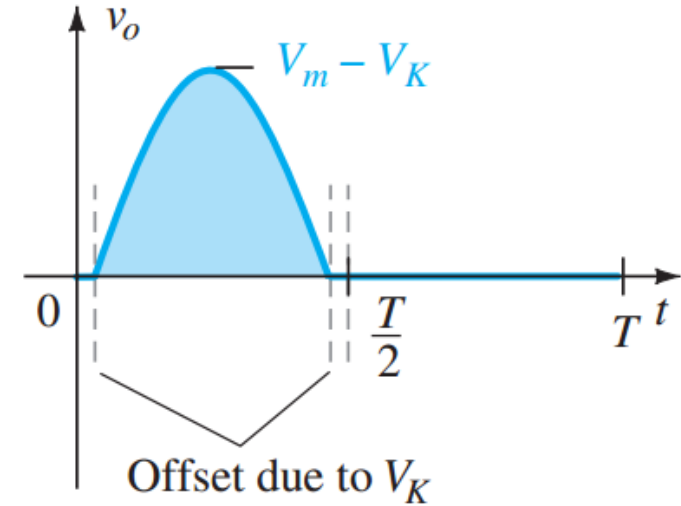
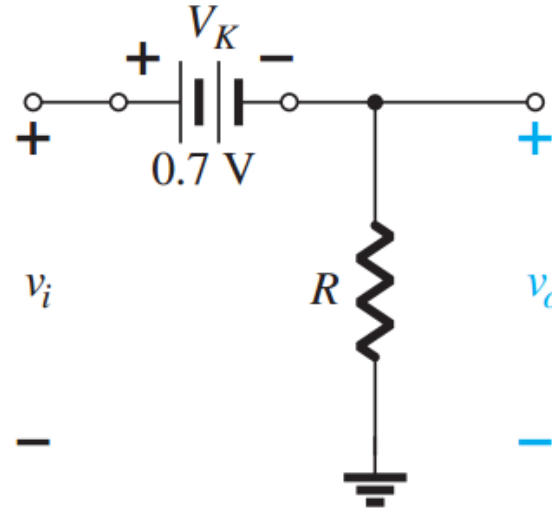
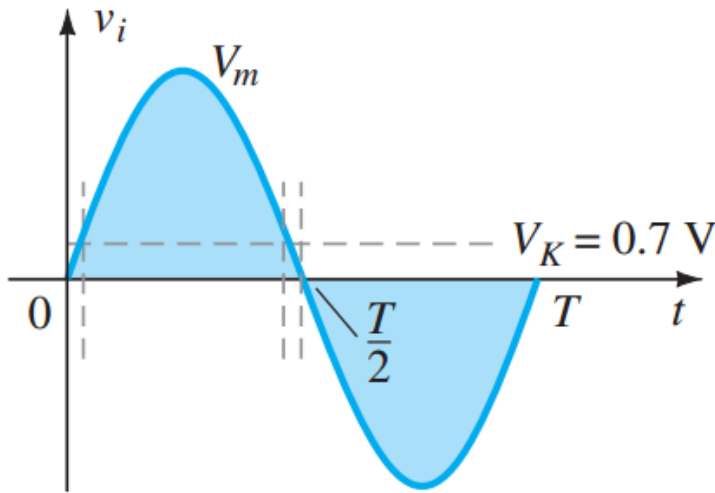
Half-wave rectified signal



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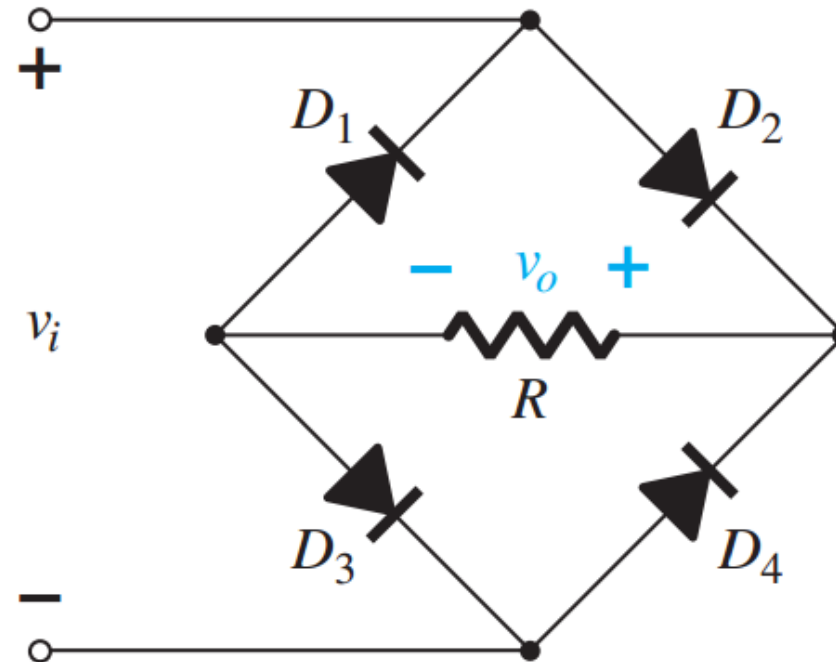
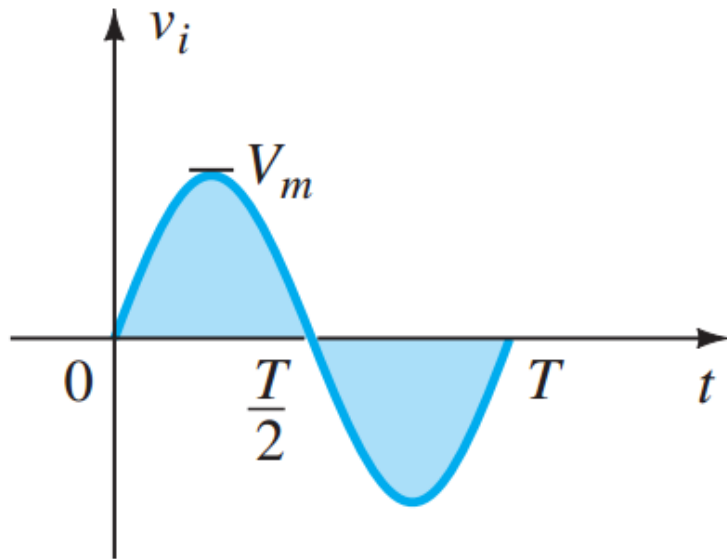
Half-wave rectified signal



$$V_{dc} \cong 0.318(V_m - V_K)$$

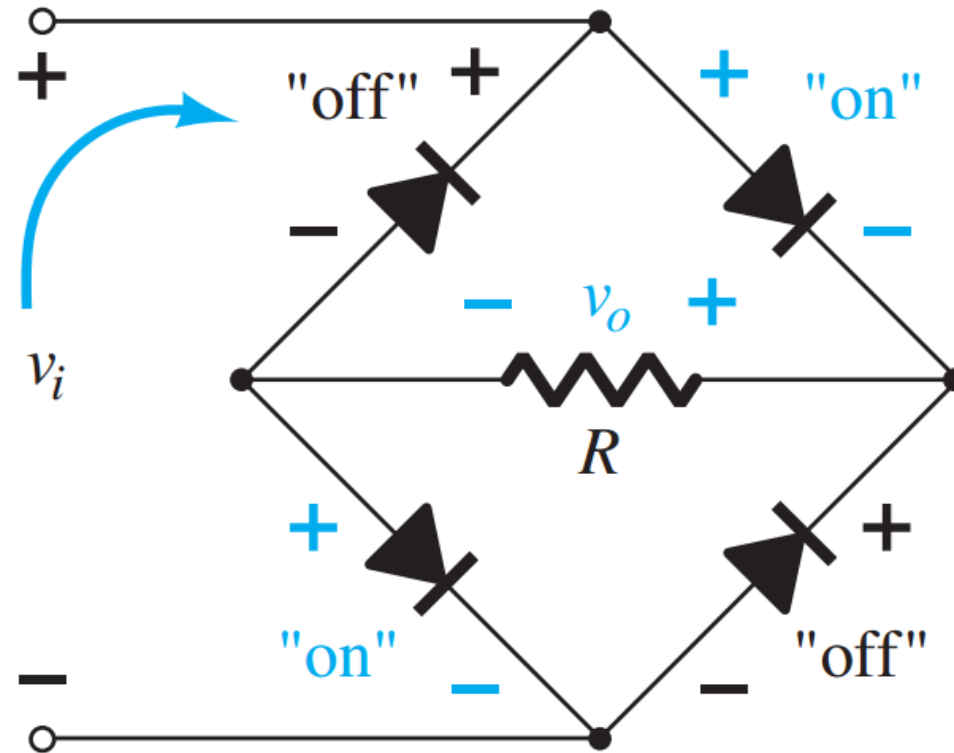
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Full-wave rectified signal



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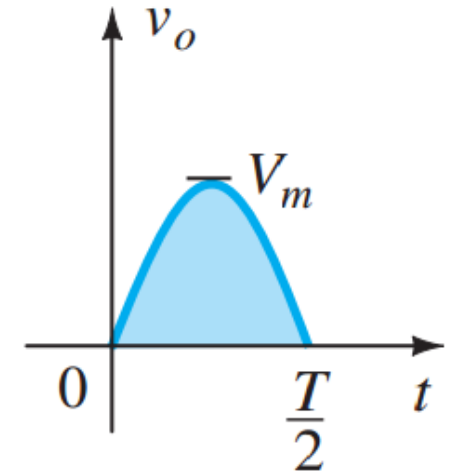
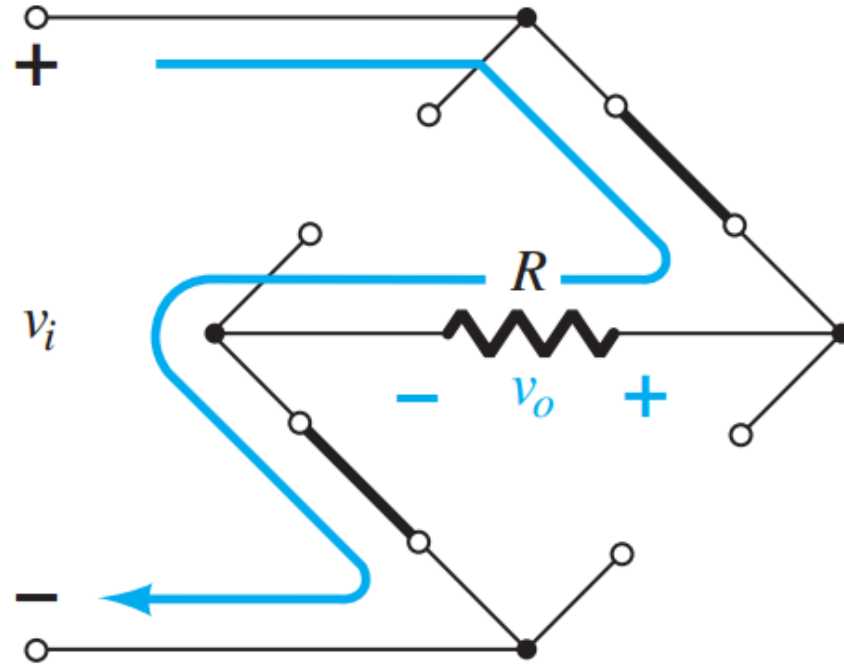
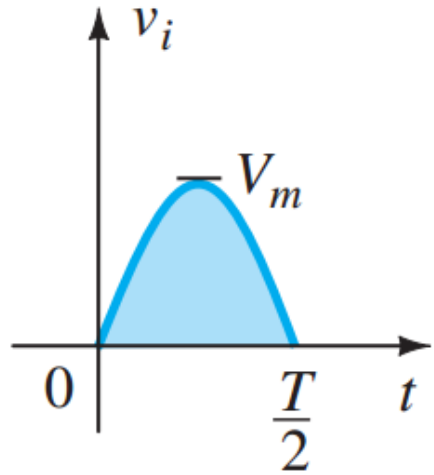
Full-wave rectified signal



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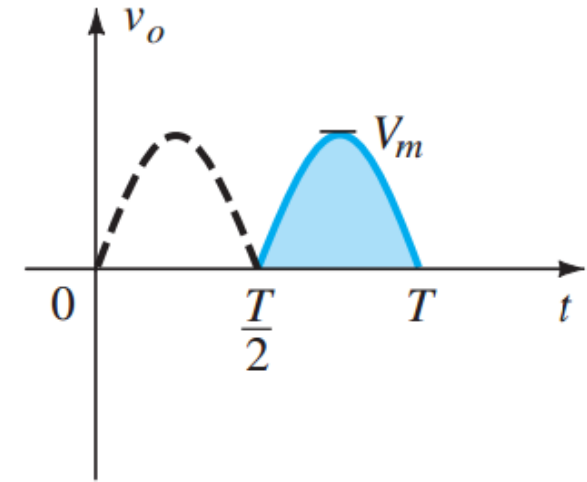
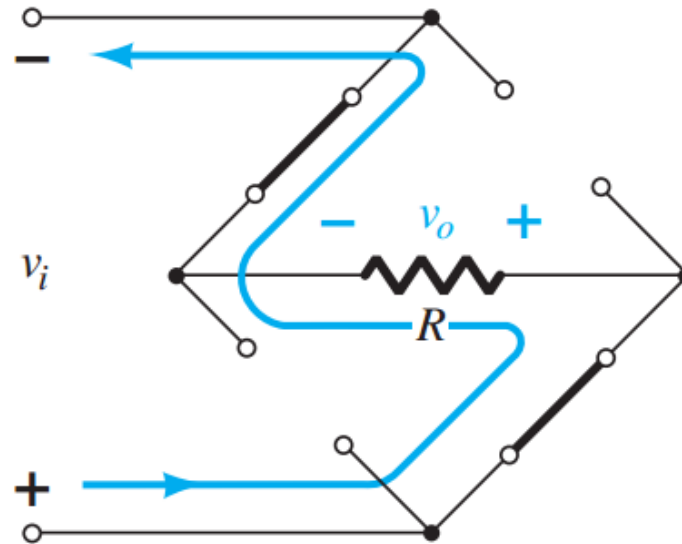
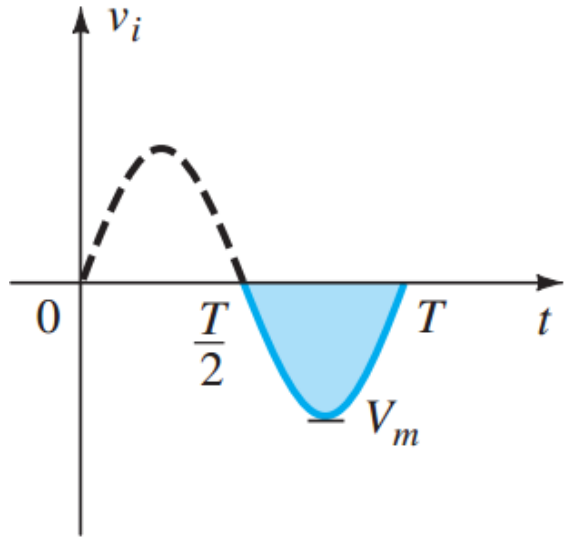


Full-wave rectified signal



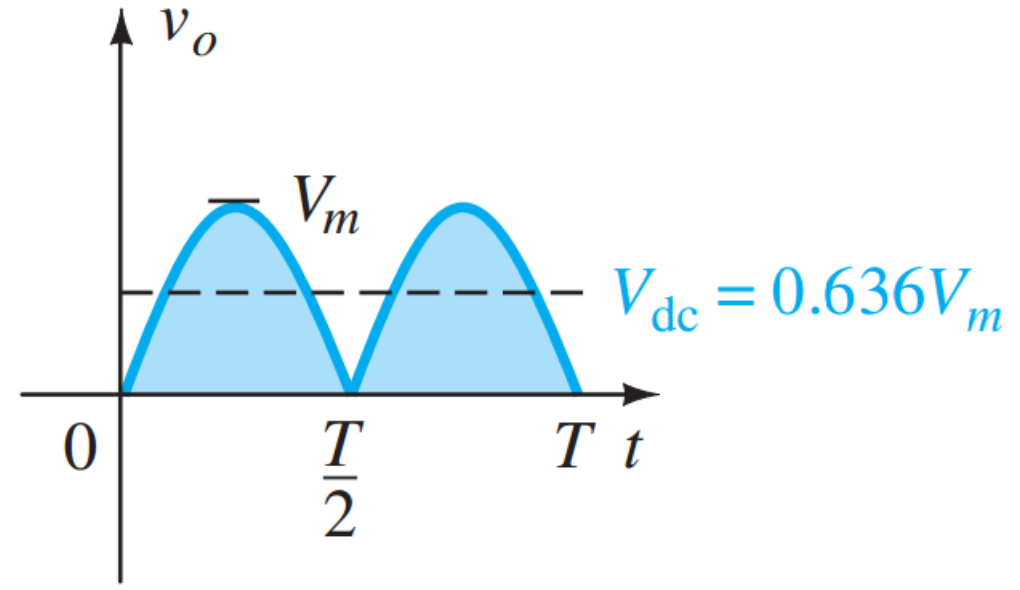
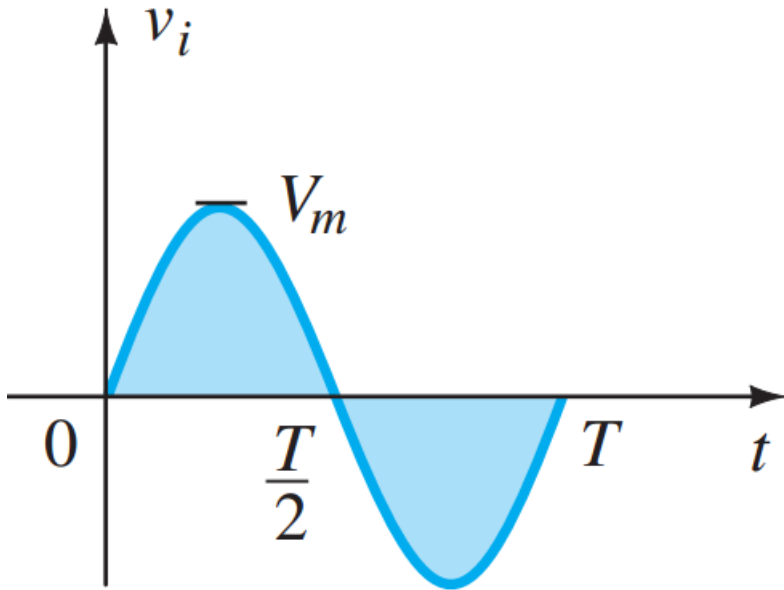
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Full-wave rectified signal



Electronic Devices and Circuit Theory – Boylestad, Nashelsky

Full-wave rectified signal

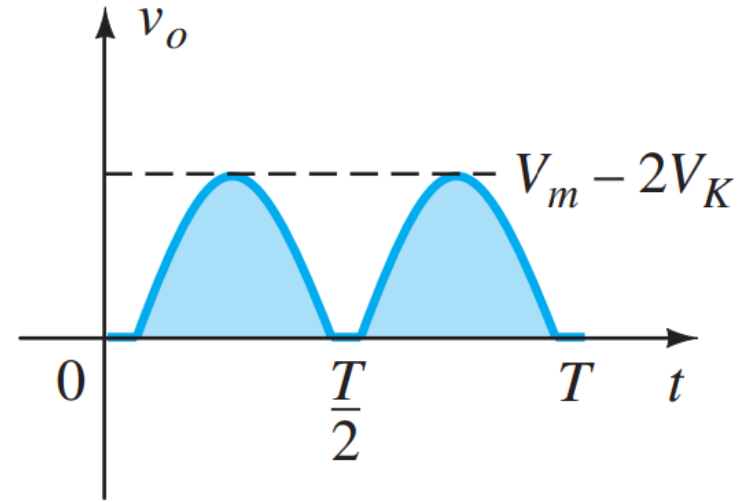
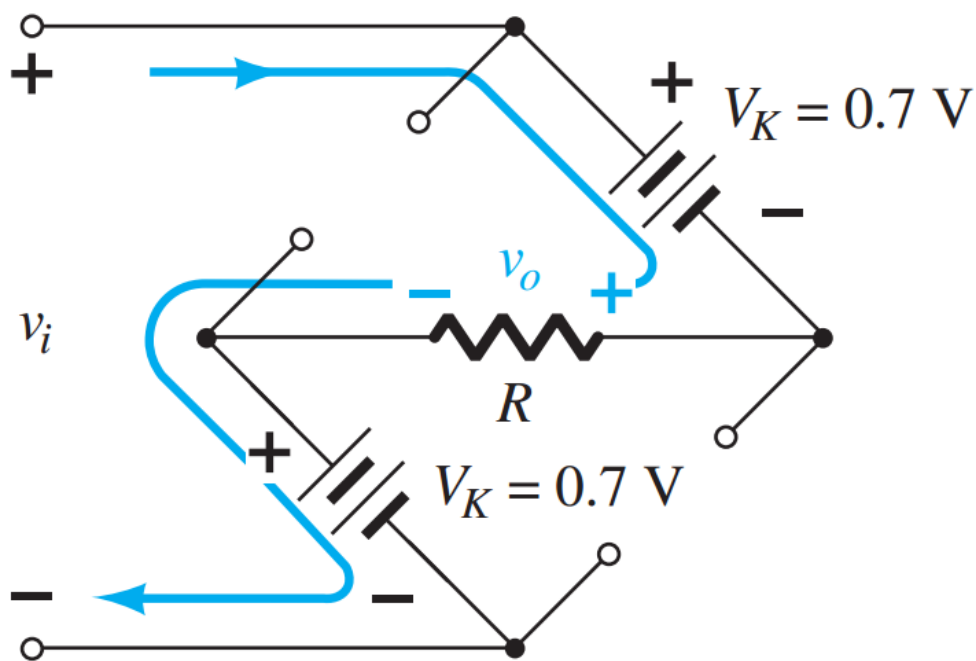


Electronic Devices and Circuit
Theory – Boylestad, Nashelsky

$$V_{dc} = 0.636 V_m$$

full-wave

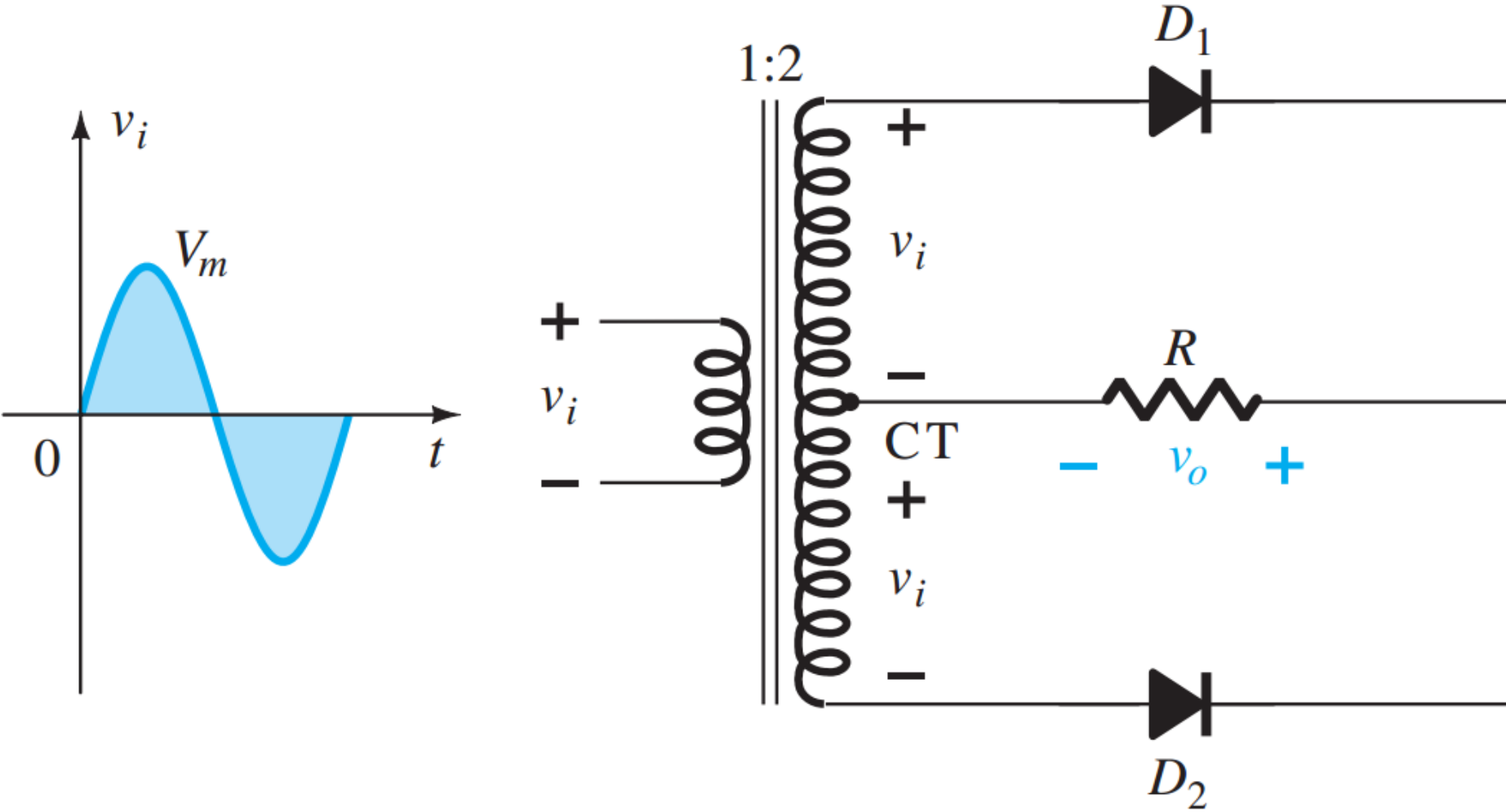
Full-wave rectified signal



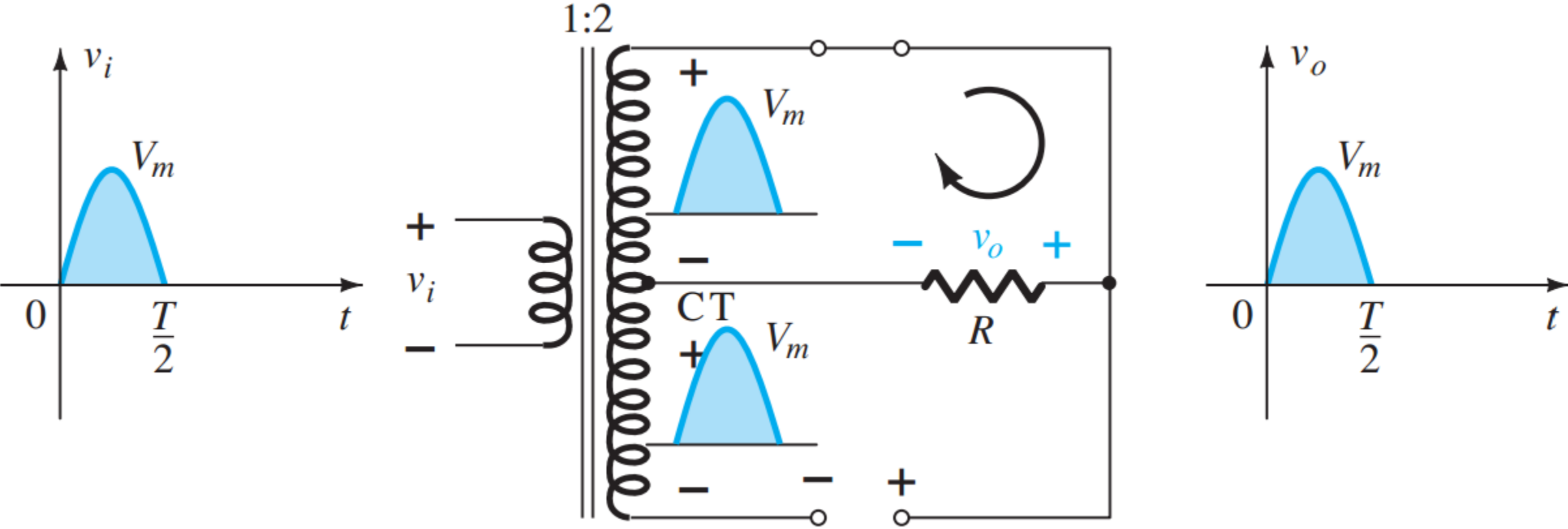
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$$V_{dc} \cong 0.636(V_m - 2V_K)$$

Center-tapped transformer full-wave rectifier



Network conditions for the positive region of input voltage



Network conditions for the negative region of input voltage

